

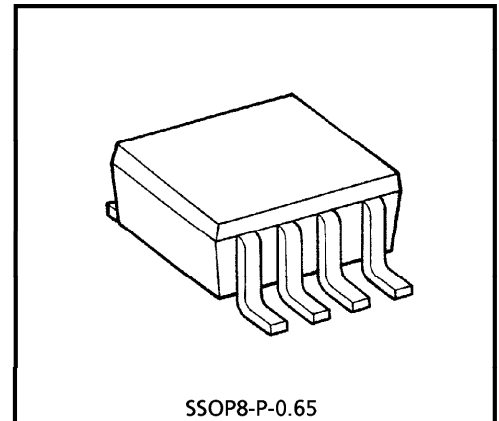
# TC7W125FU

## DUAL BUS BUFFER

The TC7W125FU is a high speed C<sup>2</sup>MOS DUAL BUS BUFFERS fabricated with silicon gate C<sup>2</sup>MOS technology. It achieve the high speed operation similar to equivalent LSTTL while maintaining the C<sup>2</sup>MOS low power dissipation.

The require 3-state control input  $\bar{G}$  to be set high to place the output into the high impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.



SSOP8-P-0.65

Weight : 0.02g (Typ.)

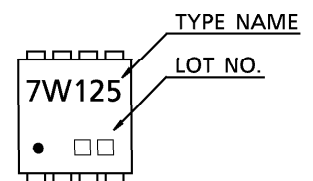
### FEATURES

- High Speed .....  $t_{pd} = 10ns$  (Typ.) at  $V_{CC} = 5V$
- Low Power Dissipation .....  $I_{CC} = 2\mu A$  (Max.) at  $T_a = 25^\circ C$
- High Noise Immunity .....  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Output Drive Capability ..... 15 LSTTL Loads
- Symmetrical Output Impedance .....  $|I_{OH}| = I_{OL} = 6mA$  (Min.)
- Balanced Propagation Delays .....  $t_{pLH} \cong t_{pHL}$
- Wide Operating Voltage Range .....  $V_{CC} (opr) = 2\sim 6V$

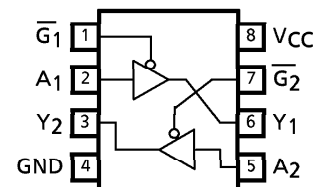
### MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7	V
DC Input Voltage	$V_{IN}$	-0.5~ $V_{CC} + 0.5$	V
DC Output Voltage	$V_{OUT}$	-0.5~ $V_{CC} + 0.5$	V
Input Diode Current	$I_{IK}$	$\pm 20$	mA
Output Diode Current	$I_{OK}$	$\pm 20$	mA
DC Output Current	$I_{OUT}$	$\pm 35$	mA
DC $V_{CC}$ / Ground Current	$I_{CC}$	$\pm 37.5$	mA
Power Dissipation	$P_D$	300	mW
Storage Temperature	$T_{stg}$	-65~150	$^\circ C$
Lead Temperature (10s)	$T_L$	260	$^\circ C$

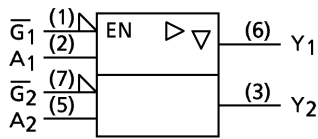
### MARKING



### PIN ASSIGNMENT (TOP VIEW)



**LOGIC DIAGRAM**



**TRUTH TABLE**

INPUTS		OUTPUTS
$\overline{G}$	A	Y
H	X	Z
L	L	L
L	H	H

X : Don't Care  
Z : High Impedance

**RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	2~6	V
Input Voltage	$V_{IN}$	0~ $V_{CC}$	V
Output Voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise and Fall Time	$t_r, t_f$	0~1000 ( $V_{CC} = 2.0V$ ) 0~500 ( $V_{CC} = 4.5V$ ) 0~400 ( $V_{CC} = 6.0V$ )	ns

**DC ELECTRICAL CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CIRCUIT	TEST CONDITION	$T_a = 25^\circ C$						UNIT				
				$V_{CC}$	MIN.	TYP.	MAX.	MIN.	MAX.					
High-Level Input Voltage	$V_{IH}$	—	—	2.0	1.5	—	—	1.5	—	V				
				4.5	3.15	—	—	3.15	—					
				6.0	4.2	—	—	4.2	—					
Low-Level Input Voltage	$V_{IL}$	—	—	2.0	—	—	0.5	—	0.5	V				
				4.5	—	—	1.35	—	1.35					
				6.0	—	—	1.8	—	1.8					
High-Level Output Voltage	$V_{OH}$	—	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -20\mu A$	2.0	1.9	2.0	—	1.9	—	V			
					4.5	4.4	4.5	—	4.4	—				
					6.0	5.9	6.0	—	5.9	—				
Low-Level Output Voltage	$V_{OL}$	—	$V_{IN} = V_{IL}$	$I_{OL} = 20\mu A$	2.0	—	0.0	0.1	—	0.1	V			
					4.5	—	0.0	0.1	—	0.1				
					6.0	—	0.0	0.1	—	0.1				
3-State Output Off-State Current	$I_{OZ}$	—	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = V_{CC}$ or GND	6.0	—	—	$\pm 0.5$	—	$\pm 5.0$	$\mu A$				
				Input Leakage Current	$I_{IN}$	—	$V_{IN} = V_{CC}$ or GND	6.0	—		—	$\pm 0.1$	—	$\pm 1.0$
								Quiescent Supply Current	$I_{CC}$		—	$V_{IN} = V_{CC}$ or GND	6.0	—

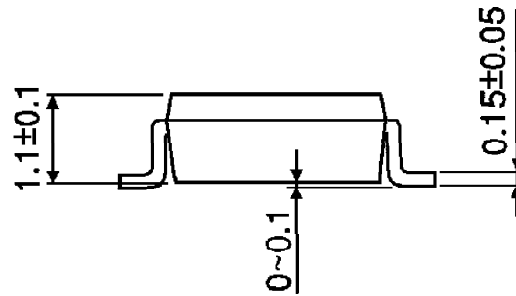
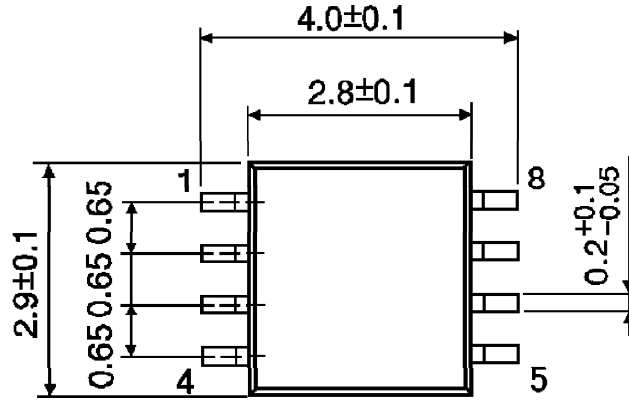
**AC ELECTRICAL CHARACTERISTICS (Input  $t_r = t_f = 6\text{ns}$ )**

PARAMETER	SYMBOL	TEST CIRCUIT	TEST CONDITION	Ta = 25°C			Ta = -40~85°C		UNIT			
				CL	VCC	MIN.	TYP.	MAX.		MIN.	MAX.	
Output Transition Time	$t_{TLH}$ $t_{THL}$	—	—	50	2.0	—	20	60	—	75	ns	
					4.5	—	6	12	—	15		
					6.0	—	5	10	—	13		
Propagation Delay Time	$t_{PLH}$ $t_{pHL}$	—	—	50	2.0	—	30	90	—	115		
					4.5	—	11	18	—	23		
					6.0	—	10	15	—	20		
					150	2.0	—	42	130	—		165
						4.5	—	14	26	—		33
						6.0	—	12	22	—		28
Output Enable Time	$t_{pZL}$ $t_{pZH}$	—	$R_L = 1\text{k}\Omega$	50	2.0	—	30	90	—	115		
					4.5	—	11	18	—	23		
					6.0	—	10	15	—	20		
					150	2.0	—	42	130	—	165	
						4.5	—	14	26	—	33	
						6.0	—	12	22	—	28	
Output Disable Time	$t_{pLZ}$ $t_{pHZ}$	—	$R_L = 1\text{k}\Omega$	50	2.0	—	24	100	—	125		
					4.5	—	12	20	—	25		
					6.0	—	10	17	—	21		
Input Capacitance	$C_{IN}$	—	—	—	—	—	5	10	—	pF		
Output Capacitance	$C_{OUT}$	—	—	—	—	—	10	—	—			
Power Dissipation Capacitance	$C_{pD}$	—	Note (1)	—	—	—	32	—	—			

Note (1) :  $C_{pD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.  
 Average operating current can be obtained by the equation :  
 $I_{CC}(\text{opr}) = C_{pD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 2$  (per Gate)

PACKAGE DIMENSIONS  
SSOP8-P-0.65

Unit : mm



Weight : 0.02g (Typ.)

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